



MICROCIRCUIT DATA SHEET

MDLM119-X REV 2A2

Original Creation Date: 07/02/01
Last Update Date: 07/11/01
Last Major Revision Date:

HIGH SPEED DUAL COMPARATOR

General Description

The LM119 precision high speed dual comparator is fabricated on a single monolithic chip. It is designed to operate over a wide range of supply voltages down to a single 5V logic supply and ground. Furthermore, it has a higher gain and lower input current than other devices. The uncommitted collector of the output stage makes the LM119 compatible with RTL, DTL and TTL as well as capable of driving lamps and relays at currents up to 25mA.

Industry Part Number

LM119

Prime Die

LM119

Controlling Document

SEE FEATURES SECTION

NS Part Numbers

LM119E-SMD
LM119H-QMLV
LM119H-SMD
LM119J-QMLV
LM119J-SMD
LM119W-QMLV
LM119W-SMD
LM119WG-QMLV
LM119WG-SMD

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp Description

| Subgrp | Description | Temp (°C) |
|--------|---------------------|------------|
| 1 | Static tests at | +25 |
| 2 | Static tests at | +125 |
| 3 | Static tests at | -55 |
| 4 | Dynamic tests at | +25 |
| 5 | Dynamic tests at | +125 |
| 6 | Dynamic tests at | -55 |
| 7 | Functional tests at | +25 |
| 8A | Functional tests at | +125 |
| 8B | Functional tests at | -55 |
| 9 | Switching tests at | +25 |
| 10 | Switching tests at | +125 |
| 11 | Switching tests at | -55 |

Features

- Two independent comparators.
- Operates from a single 5V supply.
- Typically 80nS response time at $\pm 15V$.
- Minimum fan-out of 2 each side.
- Maximum input current of 1uA over temperature.
- Inputs and outputs can be isolated from system ground.
- High common mode slew rate.

- CONTROLLING DOCUMENTS

| | |
|--------------|-----------------|
| LM119E-SMD | 86014012A |
| LM119H-QMLV | 5962-9679801VIA |
| LM119H-SMD | 8601401IA |
| LM119J-QMLV | 5962-9679801VCA |
| LM119J-SMD | 8601401CA |
| LM119W-QMLV | 5962-9679801VHA |
| LM119W-SMD | 8601401HA |
| LM119WG-QMLV | 5962-9679801VXA |
| LM119WG-SMD | 8601401X |

Although designed primarily for applications requiring operation from digital logic supplies, the LM119 is fully specified for power supplies up to $\pm 15V$. It features faster response than the LM111 at the expense of higher power dissipation. However, the high speed, wide operating voltage range and low package count make the LM119 much more versatile than older devices.

(Absolute Maximum Ratings)

(Note 1)

| | |
|---|----------------|
| Total Supply Voltage | 36V |
| Output to Negative Supply Voltage | 36V |
| Ground to Negative Supply Voltage | 25V |
| Ground to Positive Supply Voltage | 18V |
| Differential Input Voltage | ±5V |
| Input Voltage (Note 3) | ±15V |
| Power Dissipation (Note 2) | 500mW |
| Output Short Circuit Duration | 10 seconds |
| Maximum Junction Temperature | 150 C |
| Storage Temperature Range | -65 C to 150 C |
| Lead Temperature (Soldering, 10 seconds) | 260 C |
| Thermal Resistance | |
| ThetaJA | |
| E Package (Still Air) | 89 C/W |
| E Package (500LF/Min Air flow) | 63 C/W |
| H Package (Still Air) | 162 C/W |
| H Package (500LF/Min Air flow) | 88 C/W |
| J Package (Still Air) | 94 C/W |
| J Package (500LF/Min Air flow) | 52 C/W |
| W Package (Still Air) | 215 C/W |
| W Package (500LF/Min Air flow) | 132 C/W |
| WG Package (Still Air) | 215 C/W |
| WG Package (500LF/Min Air flow) | 132 C/W |
| ThetaJC | |
| E Package | 5 C/W |
| H Package | 31 C/W |
| J Package | 11 C/W |
| W Package | 13 C/W |
| WG Package | 13 C/W |
| Package Weight | |
| E Package | TBD |
| H Package | TBD |
| J Package | TBD |
| W Package | TBD |
| WG Package | 225mg |
| ESD Tolerance (Note 4) | 800V |

- Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{jmax} (maximum junction temperature), Θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{dmax} = (T_{jmax} - T_A)/\Theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower.
- Note 3: For supply voltages less than $\pm 15V$ the absolute maximum input voltage is equal to the supply voltage.
- Note 4: Human body model, 1.5K Ohm in series with 100pF.

Recommended Operating Conditions

Operating Temperature Range

-55 C \leq T_A \leq 125 C

Electrical Characteristics

DC PARAMETERS:

(The following conditions apply to all the following parameters, unless otherwise specified.)
 DC: Vcm = 0V

| SYMBOL | PARAMETER | CONDITIONS | NOTES | PIN-NAME | MIN | MAX | UNIT | SUB-GROUPS |
|--------|-------------------------|---|-------|----------|-------|-----|------|------------|
| Icc+ | Positive Supply Current | $\pm V_{CC} = \pm 15V$ | | | 11 | mA | 1 | |
| | | | | | 11.5 | mA | 2, 3 | |
| Icc- | Negative Supply Current | $\pm V_{CC} = \pm 15V$ | | | -4.2 | | mA | 1 |
| | | | | | -4.5 | | mA | 2 |
| | | | | | -6 | | mA | 3 |
| Ileak | Output Leakage Current | $+V_{CC} = 15V, -V_{CC} = -1V, V_{GND} = 0V, V_{OUT} = 35V$ | 1 | | 1.8 | uA | 1 | |
| | | | 1 | | 10 | uA | 2, 3 | |
| Iib | Input Bias Current | $\pm V_{CC} = \pm 15V$ | | | 0.475 | uA | 1 | |
| | | | | | 0.95 | uA | 2, 3 | |
| | | $V_{CC} = 5V$ | 2 | | 0.475 | uA | 1 | |
| | | | 2 | | .95 | uA | 2, 3 | |
| Vio | Input Offset Voltage | $V_{CC} = 5V, V_{CM} = 1V, R_S \leq 5K$ | 2 | | -3.8 | 3.8 | mV | 1 |
| | | | 2 | | -6.8 | 6.8 | mV | 2, 3 |
| | | $V_{CC} = 5V, V_{CM} = 3V, R_S \leq 5K$ | 2 | | -3.8 | 3.8 | mV | 1 |
| | | | 2 | | -6.8 | 6.8 | mV | 2, 3 |
| | | $\pm V_{CC} = \pm 15V, V_{CM} = 12V, R_S \leq 5K$ | | | -3.8 | 3.8 | mV | 1 |
| | | | | | -6.8 | 6.8 | mV | 2, 3 |
| | | $\pm V_{CC} = \pm 15V, V_{CM} = -12V, R_S \leq 5K$ | | | -3.8 | 3.8 | mV | 1 |
| | | | | | -6.8 | 6.8 | mV | 2, 3 |
| Iio | Input Offset Current | $V_{CC} = 5V, V_{CM} = 1V$ | 2 | | -75 | 75 | nA | 1 |
| | | | 2 | | -100 | 100 | nA | 2, 3 |
| | | $V_{CC} = 5V, V_{CM} = 3V$ | 2 | | -75 | 75 | nA | 1 |
| | | | 2 | | -100 | 100 | nA | 2, 3 |
| | | $\pm V_{CC} = \pm 15V, V_{CM} = 12V$ | | | -75 | 75 | nA | 1 |
| | | | | | -100 | 100 | nA | 2, 3 |
| | | $\pm V_{CC} = \pm 15V, V_{CM} = -12V$ | | | -75 | 75 | nA | 1 |
| | | | | | -100 | 100 | nA | 2, 3 |
| Vi | Input Voltage Range | $V_{CC} = 5V$ | 2, 3 | | 1 | 3 | V | 1, 2, 3 |
| | | $V_{CC} = \pm 15V$ | 3 | | -12 | 12 | V | 1, 2, 3 |

Electrical Characteristics

DC PARAMETERS: (Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)
 DC: $V_{cm} = 0V$

| SYMBOL | PARAMETER | CONDITIONS | NOTES | PIN-NAME | MIN | MAX | UNIT | SUB-GROUPS |
|--------|-----------------------------|---|-------|----------|------|-----|------|------------|
| Vsat | Output Saturation Voltage | Vcc = $\pm 15V$, $I_{out} = 25mA$, $V_{in} \leq -5mV$ | 1 | | | 1.5 | V | 1, 2, 3 |
| | | +Vcc = 3.5V, -Vcc = -1V, $V_{in} \leq -6mV$, $I_{sink} \leq 3.2mA$ | | | | 0.4 | V | 1, 2 |
| | | | | | | 0.6 | V | 3 |
| Av | Voltage Gain | $\pm V_{cc} = \pm 15V$, Delta $V_{out} = 12V$ | 4 | | 10.5 | | K | 4 |
| | | | 4 | | 10 | | K | 5, 6 |
| | | $V_{cc} = 5V$, Delta $V_{out} = 4.5V$ | 2, 4 | | 8 | | K | 4 |
| | | | 2, 4 | | 5 | | K | 5 |
| | | | 2, 4 | | 5.8 | | K | 6 |
| CMRR | Common Mode Rejection Ratio | $\pm V_{cc} = \pm 15V$, $V_{cm} = \pm 12V$ | | | 80 | | dB | 4 |

DC PARAMETERS: DRIFT VALUES

(The following conditions apply to all the following parameters, unless otherwise specified.)
 DC: $V_{cm} = 0V$. Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 ONLY.

| | | | | | | | | |
|------|-------------------------|---|--|--|------|-----|----|---|
| Icc+ | Positive Supply Current | $\pm V_{cc} = \pm 15V$ | | | -1 | 1 | mA | 1 |
| Icc- | Negative Supply Current | $\pm V_{cc} = \pm 15V$ | | | -0.5 | 0.5 | mA | 1 |
| Vio | Input Offset Voltage | $V_{cc} = 5V$, $V_{cm} = 1V$, $R_s \leq 5K$ | | | -0.4 | 0.4 | mV | 1 |

Note 1: $V_{in} \geq 8mV$ at extremes for I_{leak} and $V_{in} \leq -8mV$ at extremes for Vsat (V_{in} to exceed V_{os}).

Note 2: 5 Volt differential across +Vcc and -Vcc.

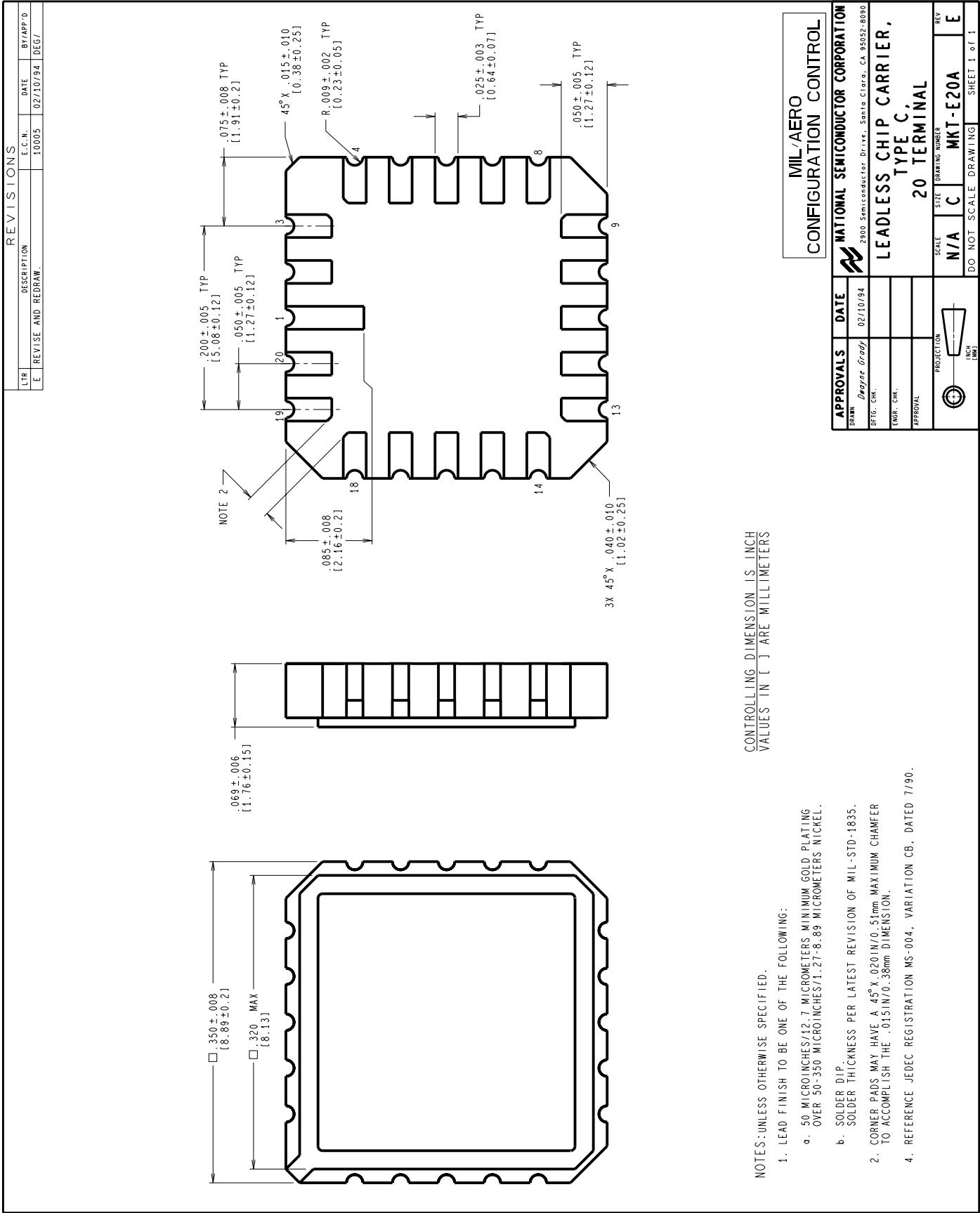
Note 3: Parameter guaranteed by Vio and Iio tests.

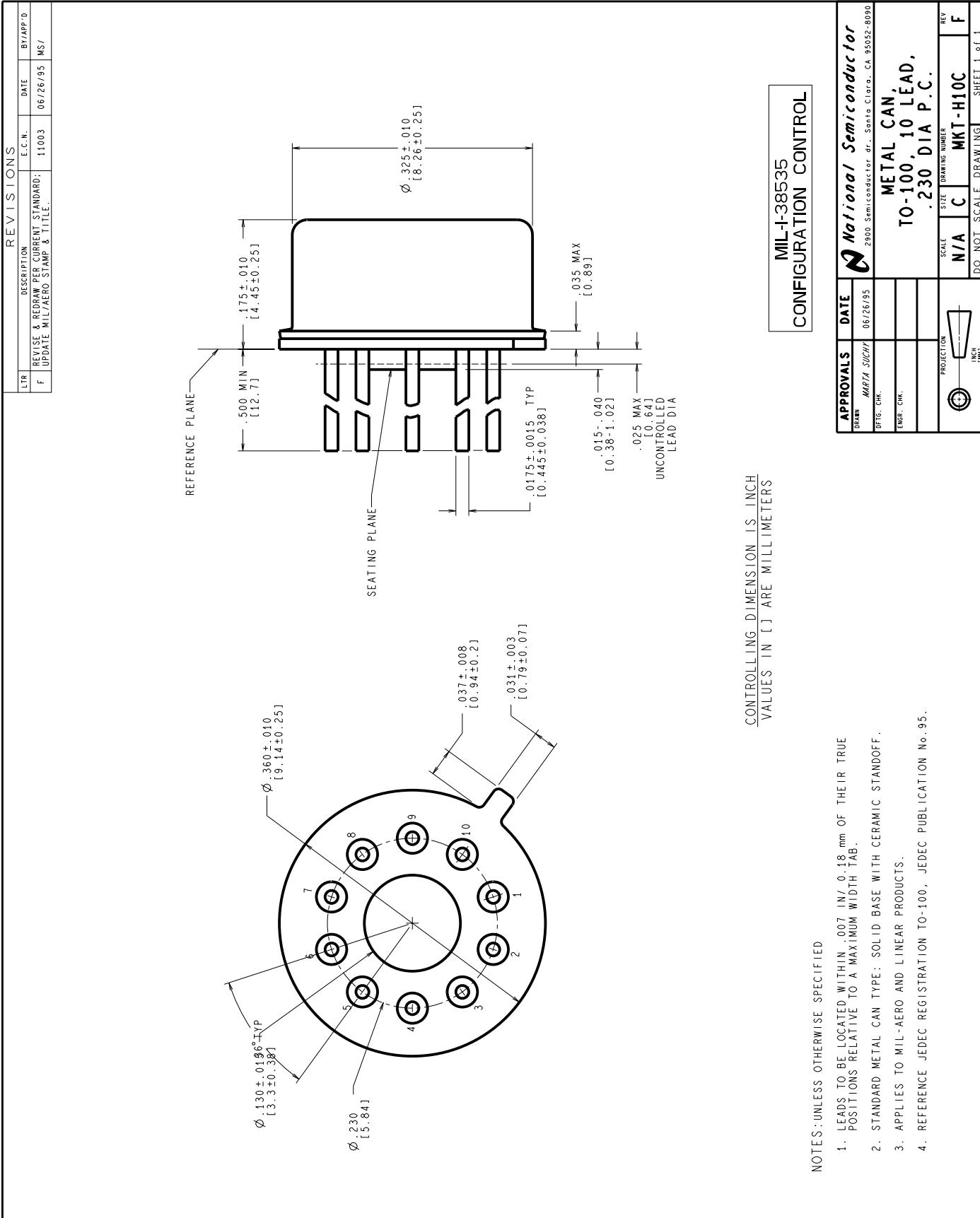
Note 4: K = V/mV.

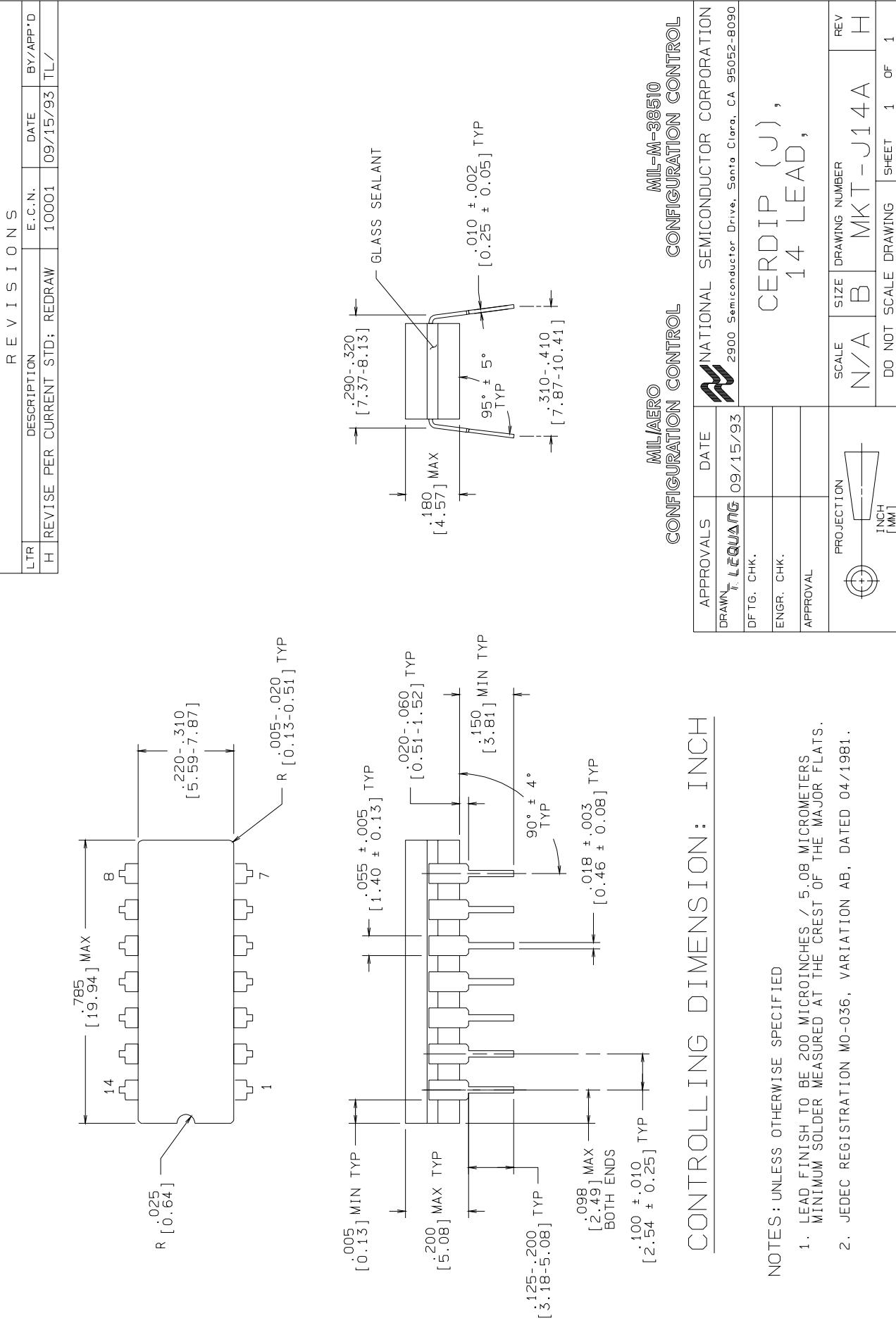
Graphics and Diagrams

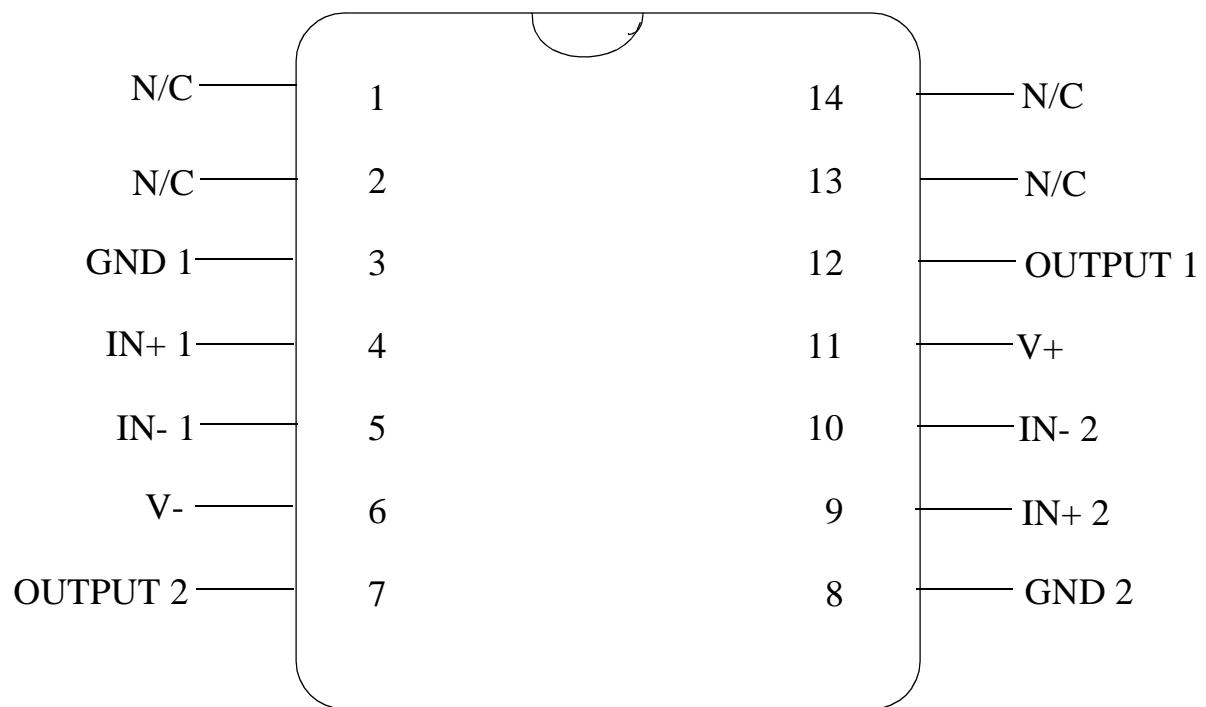
| GRAPHICS# | DESCRIPTION |
|-----------|--|
| 06142HRA3 | LCC (E), TYPE C, 20 TERMINAL (B/I CKT) |
| 08906HRB3 | METAL CAN (H), 10 LEAD (B/I CKT) |
| 09078HRB3 | CERPACK (W), 10 LEAD (B/I CKT) |
| 09641HRA2 | CERDIP (J), 14 LEAD (B/I CKT) |
| E20ARE | LCC (E), TYPE C, 20 TERMINAL(P/P DWG) |
| H10CRF | METAL CAN (H), TO-100, 10LD, .230 DIA PC (P/P DWG) |
| J14ARH | CERDIP (J), 14 LEAD (P/P DWG) |
| P000182A | CERDIP (J), 14 LEAD (PINOUT) |
| P000196A | LCC (E), 20 LEAD (PINOUT) |
| P000197A | METAL CAN (H), TO-100, 10 LD, .230 DIA PC (PINOUT) |
| P000198A | CERPACK (W), 10 LEAD (PINOUT) |
| P000237A | CERAMIC SOIC (WG), 10 LEAD (PINOUT) |
| W10ARG | CERPACK (W), 10 LEAD (P/P DWG) |
| WG10ARC | CERAMIC SOIC (WG), 10 LEAD (P/P DWG) |

See attached graphics following this page.

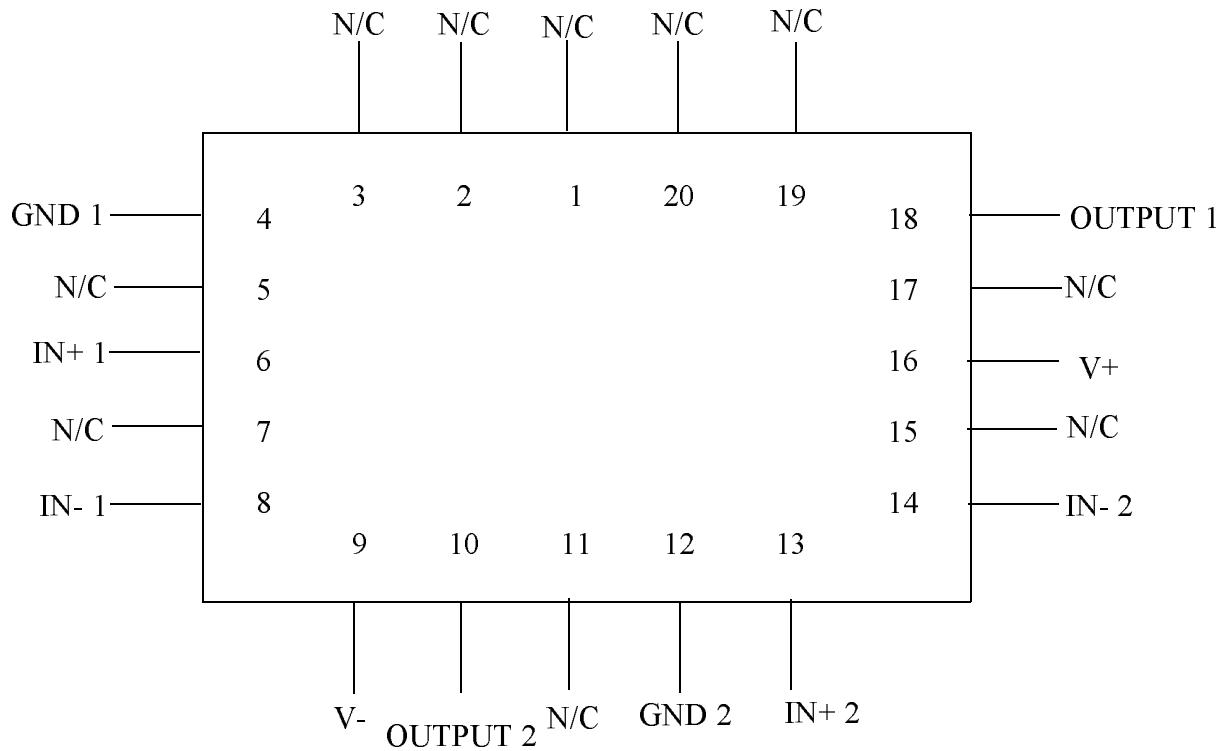




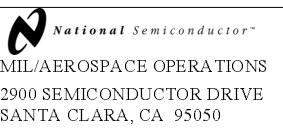


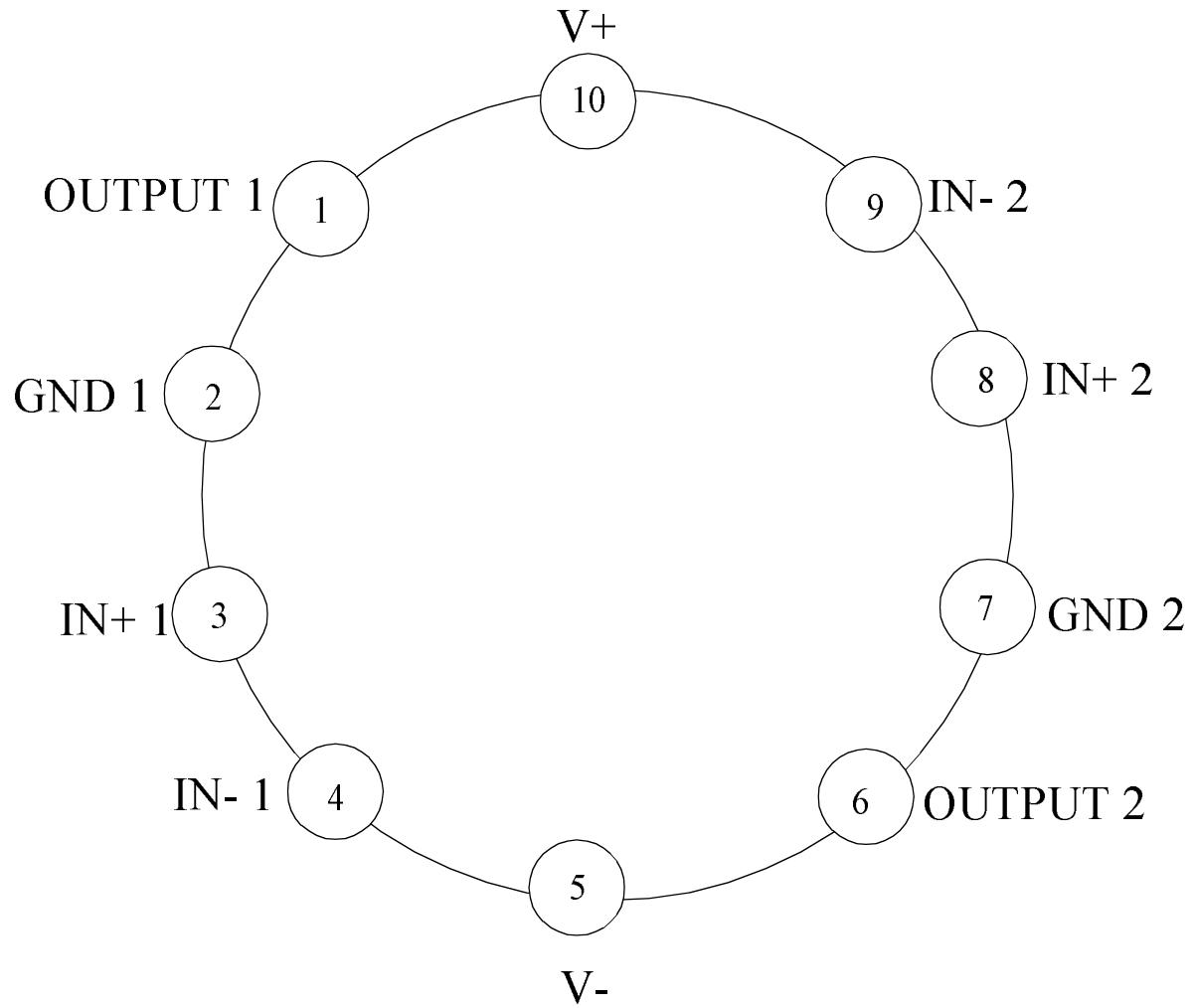


LM119J
14 - LEAD DIP
CONNECTION DIAGRAM
TOP VIEW
P000182A

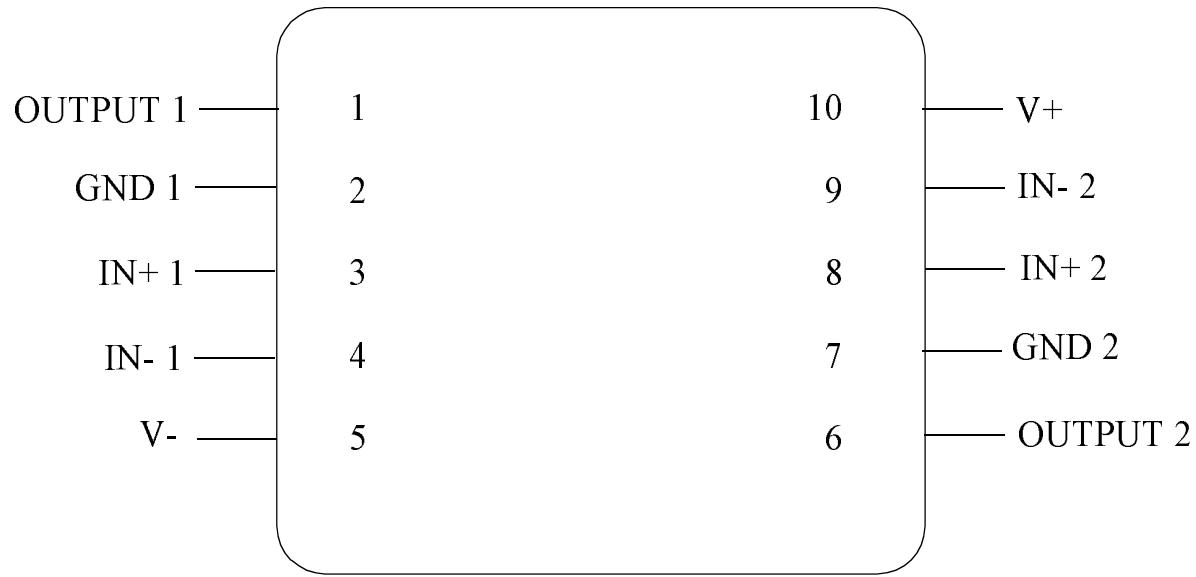


LM119E
20 - LEAD LCC
CONNECTION DIAGRAM
TOP VIEW
P000196A

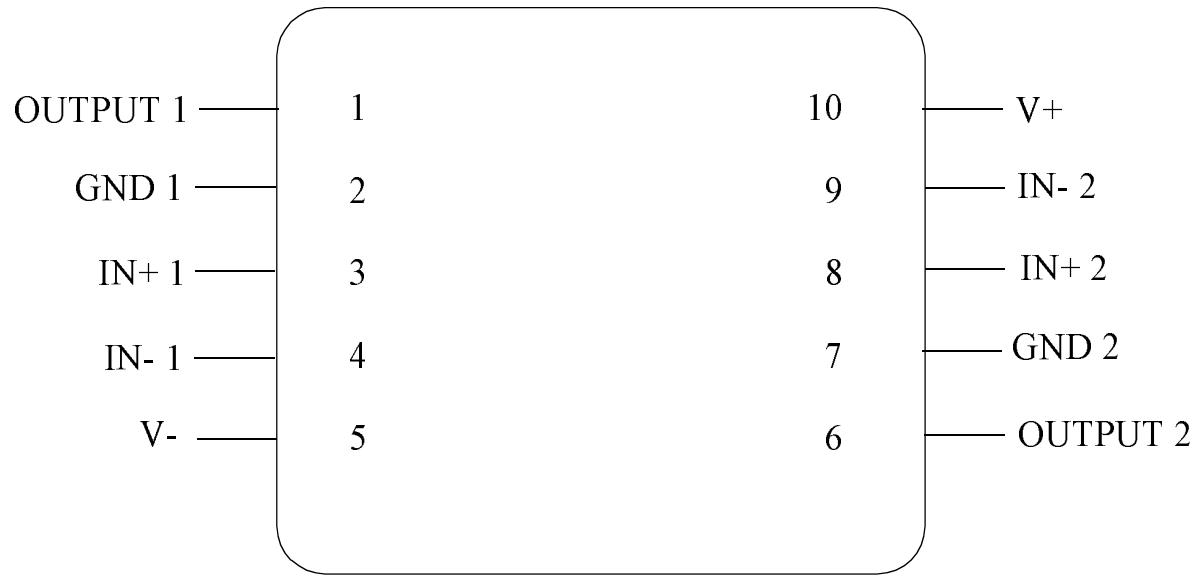




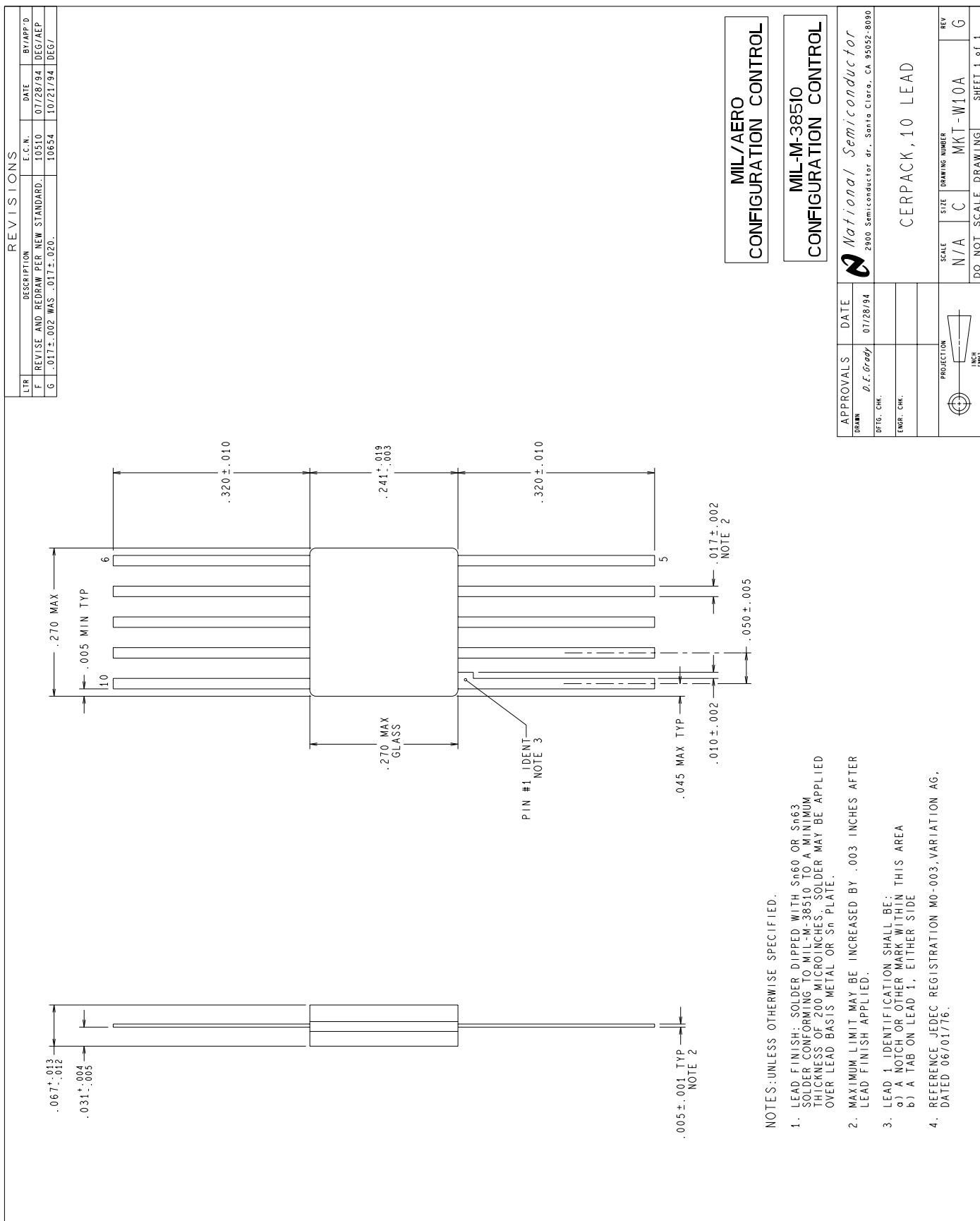
LM119H
10 - PIN METAL CAN
CONNECTION DIAGRAM
TOP VIEW
P000197A

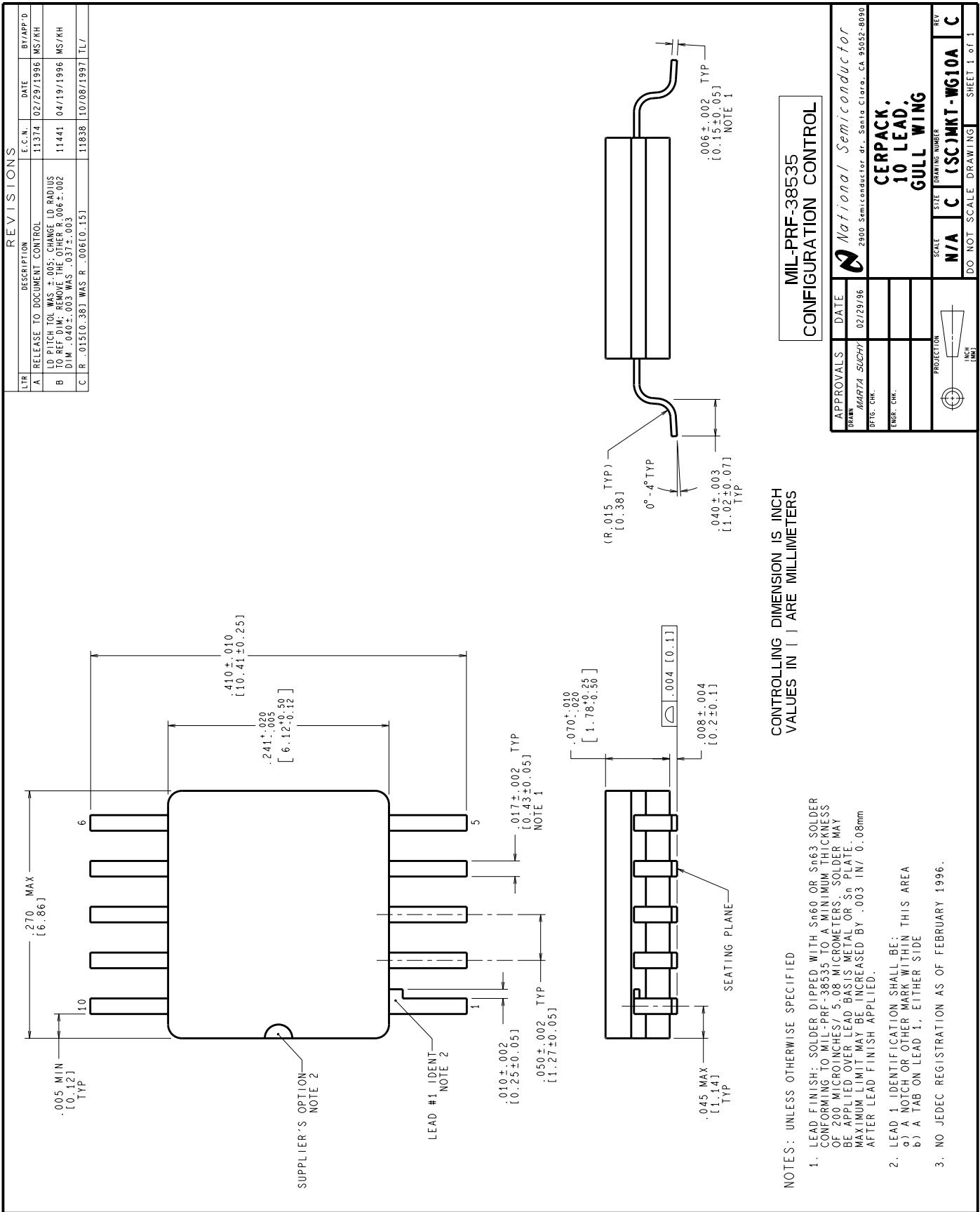


LM119W
10 - LEAD CERPACK
CONNECTION DIAGRAM
TOP VIEW
P000198A



LM119WG
10 - LEAD CERAMIC SOIC
CONNECTION DIAGRAM
TOP VIEW
P000237A





Revision History

| Rev | ECN # | Rel Date | Originator | Changes |
|------------|--------------|-----------------|-------------------|--|
| 0B0 | M0001371 | 02/25/98 | Barbara Lopez | Added Power Dissipation - Note 2 in Absolute section. Renumbered all other notes. Archive MDS - MDLM119-X Rev. 0A0. Release MDS - MDLM119-X Rev. 0B0. |
| 0C1 | M0002726 | 12/06/99 | Barbara Lopez | Update MDS: MDLM119-X Rev. 0B0 to MDLM119-X Rev. 0C1. Added WG package to MDS. Added MKT outline, Burn-In CKT and Pinouts. |
| 1C1 | M0003596 | 12/06/99 | Rose Malone | Archive MDLM119-X, Rev. 0C1. MDS replaced by MDLM119-X-RH, Rev. 0A0. MDS is being archived as Rev. 1C1. |
| 2A2 | M0003821 | 07/11/01 | Rose Malone | De-Archived MDS: MDLM119-X, Re-Instate back into system at Rev. 2A2. Removed Rad Devices, MDLM119-X references Non Rad Devices ONLY. MDLM119-X, Rev. 2A2 replaces MDLM119-X-RH |